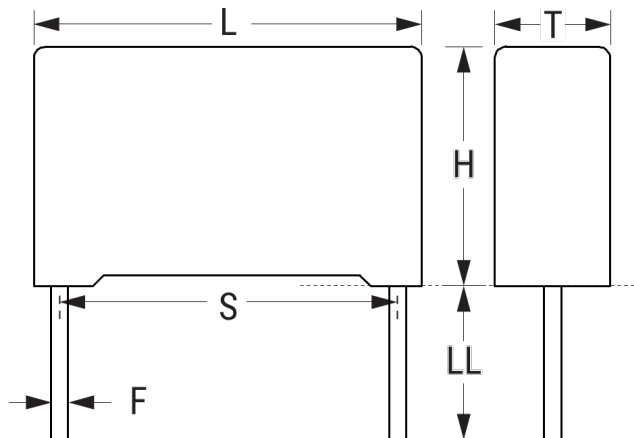


R41BW412050TOK

Aliases (41BW412050TOK)

R41B, Film, Metallized Polypropylene, Automotive Safety, 1.2 uF, 10%, 300 VAC (X1), 350 VAC (Y2), 125°C, 37.5mm



Click [here](#) for the 3D model.

Dimensions

L	41.5mm +0.3/-0.5mm
H	40mm +0.1/-0.5mm
T	20mm +0.2/-0.5mm
S	37.5mm +/-0.4mm
LL	25mm +2/-1mm
F	1mm +/-0.05mm

Packaging Specifications

Packaging	Tray
Packaging Quantity	84

General Information

Series	R41B
Dielectric	Metallized Polypropylene
Style	Radial
Features	Automotive Grade, EMI Safety
RoHS	Yes
Lead	Wire Leads
Safety Class	X1/Y2
Qualifications	AEC-Q200, ENEC, UL, cUL, CQC
AEC-Q200	Yes
THB Performance	Yes
Typical Component Weight	38.87 g

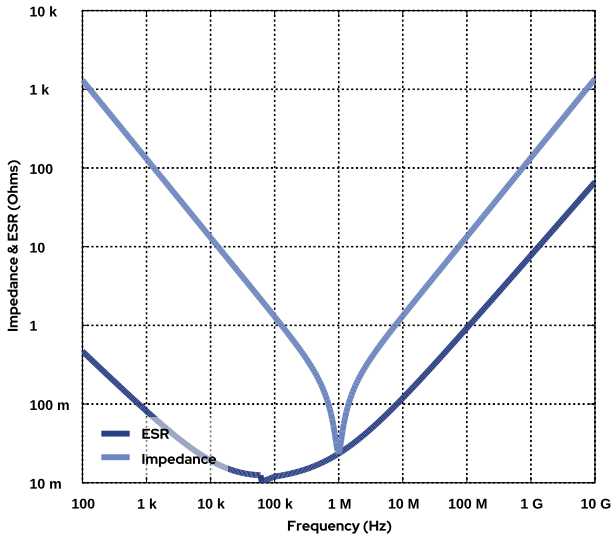
Specifications

Capacitance	1.2 uF
Capacitance Tolerance	10%
Voltage AC	300 VAC (X1), 350 VAC (Y2)
Temperature Range	-40/+125°C
Rated Temperature	125°C
Dissipation Factor	0.2% 1kHz
Insulation Resistance	30 GOhms
Max dV/dt	300 V/us

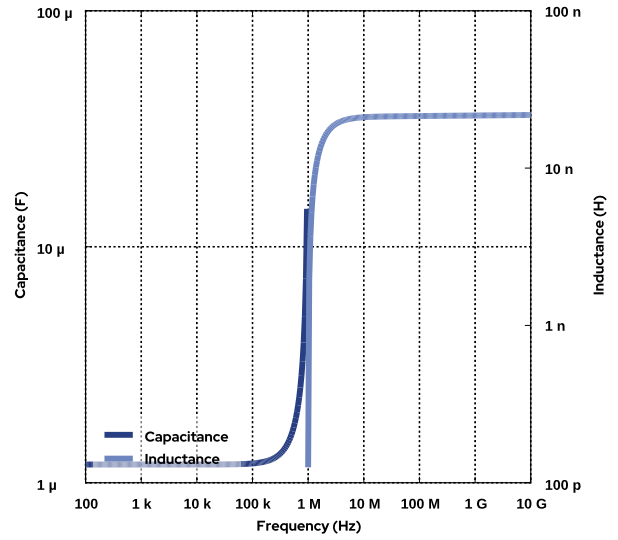
Simulations

For the complete simulation environment please visit [K-SIM](#).

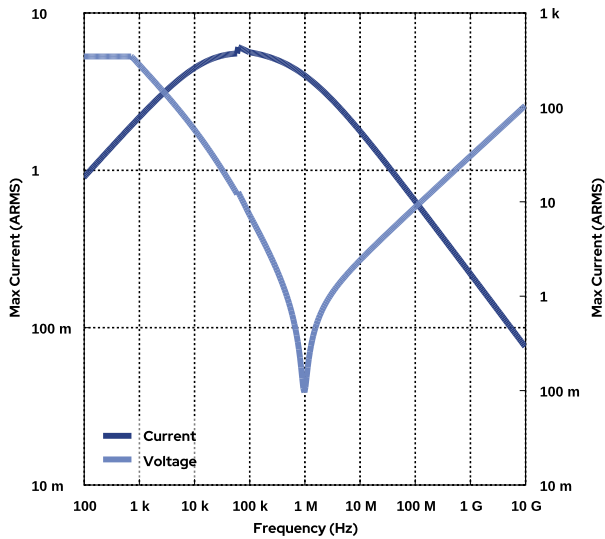
Impedance and ESR



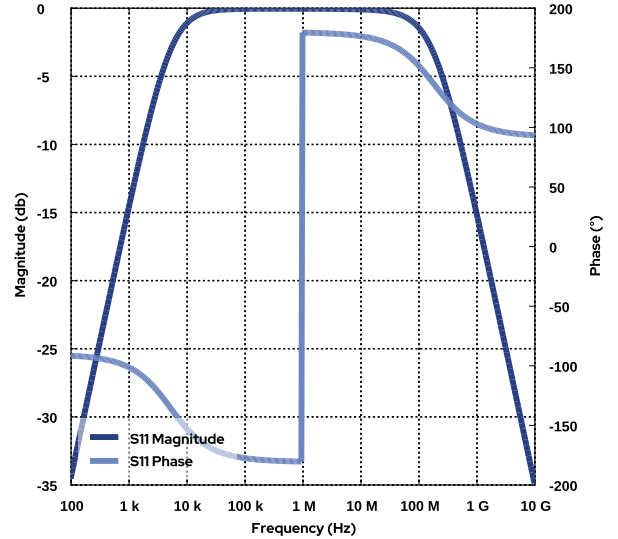
Capacitance and Inductance



Current and Voltage



S11



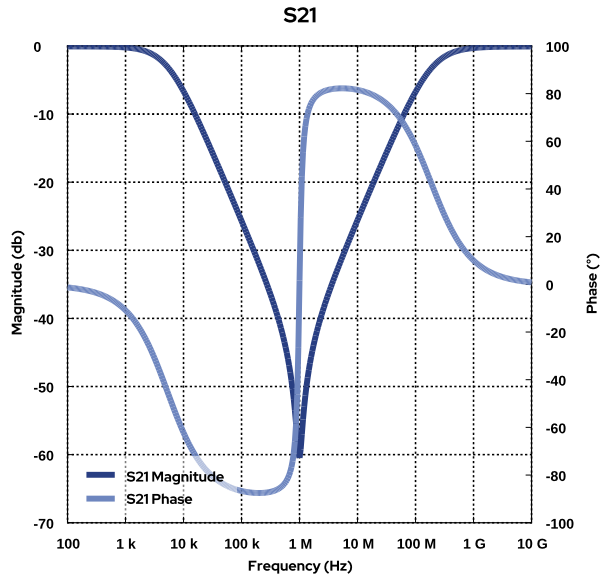


a YAGEO company

R41BW412050TOK

Aliases (41BW412050TOK)

R41B, Film, Metallized Polypropylene, Automotive Safety, 1.2 uF, 10%, 300 VAC (X1), 350 VAC (Y2), 125°C, 37.5mm



These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.
- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance).
- The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages generated at any other harmonics.
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.